

DIP6, 1 Form A 1500V High Sensitivity PhotoMOS Relay

## Description

The JOR258HD6 photorelay consists of infrared light-emitting diode, photoelectric generator, and optical MOSFET coupling.



## Features

- Load voltage: 1,500 V
- Load current: 20 mA
- Distance between output terminals are longer than 6-pin DIP package

## Applications

- Isolation detection
- Voltage monitoring
- Signal control

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|                                | DIP6, 1 Fo               | orm A 1500V          | High Sens | sitivity Pho | toMOS R |  |  |
|--------------------------------|--------------------------|----------------------|-----------|--------------|---------|--|--|
| ABSOLUTE MAXIMUM RATINGS       |                          |                      |           |              |         |  |  |
|                                | PARAMETER                | SYMBOL               | Rating    | UNIT         |         |  |  |
| Input –                        | Forward Current          | Forward Current      |           | 20           | mA      |  |  |
|                                | Reverse Voltage          |                      | Vr        | 6            | V       |  |  |
|                                | Junction Temperatur      | Junction Temperature |           | 125          | °C      |  |  |
|                                | Power Dissipation        |                      | Р         | 50           | mW      |  |  |
|                                | Load voltage (peak AC)   |                      | VL        | 1500         | V       |  |  |
|                                | Continuous load current  |                      | ١L        | 20           | mA      |  |  |
| Output                         | Peak load current        |                      | lpeak     | 60           | mA      |  |  |
|                                | Junction Temperature     |                      | ιT        | 125          | °C      |  |  |
|                                | Output Power Dissipation |                      | Ро        | 360          | mW      |  |  |
| Total Power Dissipation        |                          |                      | Ptot      | 400          | mW      |  |  |
| Isolation Voltage (Note 1)     |                          |                      | Viso      | 5000         | Vrms    |  |  |
| Operating Temperature          |                          | Topr                 | -40~+110  | °C           |         |  |  |
| Storage Temperature            |                          | Tsig                 | -55~+150  | °C           |         |  |  |
| Soldering Temperature (Note 2) |                          | Tsol                 | 260       | °C           |         |  |  |

Note: Ambient temperature = 25°C, unless otherwise specified. Stresses exceeding the absolute maximum ratings can cause permanent damage to the device. Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

Note 1: AC For 1 Minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

Note 2: For 10 Seconds

| RECOMMENDED OPERATION CONDITIONS |                         |        |      |      |      |  |
|----------------------------------|-------------------------|--------|------|------|------|--|
| CH                               | IARACTERISTICS          | SYMBOL | MIN. | MAX. | UNIT |  |
| LED Forward Current              |                         | lF     | 1    | 5    | mA   |  |
| JOR258HD6                        | Load voltage (Peak AC)  | VL     | -    | 1200 | V    |  |
|                                  | Continuous load current | IL.    | -    | 20   | mA   |  |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

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| ELECTRICAL OPTICAL CHARACTERISTICS |                |         |       |         |          |                       |  |  |
|------------------------------------|----------------|---------|-------|---------|----------|-----------------------|--|--|
| PARAMETER                          | SYMBOL         | MIN.    | TYP.  | MAX.    | UNIT     | TEST CONDITION        |  |  |
| INPUT CHARACTERISTICS              |                |         |       |         |          |                       |  |  |
| Forward Voltage                    | V <sub>F</sub> | -       | 1.8   | 2.2     | V        | I <sub>F</sub> = 1 mA |  |  |
| Reverse Current                    | IR             | -       | 0.05  | 10      | uA       | Vr=5V                 |  |  |
| OUTPUT CHARACTERISTICS             |                |         |       |         |          |                       |  |  |
| Off state leakage current          | lLeak          | _       | - 0.1 | 0.1 10  | uA       | IF=0mA                |  |  |
|                                    | ILeak          | -       |       |         |          | VL = Max              |  |  |
| On resistance                      | Ron            | -       | - 270 | 70 500  | v        | IF=1mA                |  |  |
|                                    | Kon            |         | 500   | v       | IL = Max |                       |  |  |
| COUPLE CHARACTERISTICS             |                |         |       |         |          |                       |  |  |
| LED operate current                | IFON           | -       | 0.1   | 1       | mA       | IL=20mA               |  |  |
| LED turn off voltage               | VFOFF          | 0.8     | 1.7   |         | V        | IL≦10 μ A             |  |  |
| Turn on time                       | TON            | Ton - C | 0.2   | 1       | ms       | IF=1mA                |  |  |
| Turn on time                       |                |         |       |         |          | IL = Max              |  |  |
| Turn off time                      | Toff           |         | 0.1   | 0.1 0.2 | ms       | IF=1mA                |  |  |
|                                    | IUFF           |         | 0.1   |         |          | IL = Max              |  |  |

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| DIP6, 1 Form                            | A 1500V High Sensitivity PhotoMOS Relay  |  |  |  |  |  |
|---|--|--|--|--|--|--|
| MARKING INFORMATION                     |  |  |  |  |  |  |
| JOR<br>258H<br>YAWW                     | JOR : Company Abbr.<br>258H : Part Number<br>Y : Fiscal Year<br>A : Manufacturing Code<br>WW : Work Week |  |  |  |  |  |
| ORDERING INFORMATION                    | LABEL INFORMATION  |  |  |  |  |  |
| JOR258HDX(Y)(Z)-G<br>JOR – Company Abbr | ▶ 捷捷微电(深圳)有限公司<br>JIEJIE MICROELECTRONICS (Shenzhen) Co Ltd  |  |  |  |  |  |
| 258H – Part Number                      | Part No.: XXXXXXXXX Bin Code: X  |  |  |  |  |  |
| D – DIP or SMD Package                  |  |  |  |  |  |  |
| X – 6(Pin Count)                        | Date Code: XXXX  |  |  |  |  |  |
| Y – Lead Form Option (SL/None)          | QTY: XXX PCS 回题<br>建設設   |  |  |  |  |  |
| Z – Tape and Reel Option (T1/T2)        |  |  |  |  |  |  |
| G – Green                               |  |  |  |  |  |  |

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## Precautions for Soldering

### IR Reflow soldering

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.



| Time | (S) |
|------|-----|
|------|-----|

|   | Symbol         | Min | Max | Unit |
|---|----------------|-----|-----|------|
| Preheat temperature                             | Ts             | 150 | 200 | °C   |
| Preheat time                                    | ts             | 60  | 120 | S    |
| Ramp-up rate (T∟ to T <sub>P</sub> )            |                |     | 3   | °C/s |
| Liquidus temperature                            | ΤL             | 21  | °C  |      |
| Time above T∟                                   | t∟             | 60  | 100 | S    |
| Peak Temperature                                | Τ <sub>Ρ</sub> |     | 260 | °C   |
| Time during which $T_{C}$ is                    | <b>+</b> _     |     | 20  | 0    |
| between (T <sub>P</sub> - 5) and T <sub>P</sub> | tP             |     | 20  | S    |
| Ramp-down rate                                  |                |     | 6   | °C/s |

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